REVISIONS Device type 01 inactive for new design as of 22 September 1978. DATE **APPROVED** DESCRIPTION LTR Use M38510/31512B--. Change maximum clock frequency (f_{MAX}), group A subgroups 10 and 11 16 JUNE 1987 at 15 pF from 20 MHz to 15 MHz and at 50 pF from 15 MHz to 13 MHz. Subgroups 10 and 11, t_{PHL2} at 15 pF from 35 ns to 38 ns max and t_{PLH2} at 15 pF from 31 ns to 34 ns max. Change to military drawing format. Editorial changes throughout. Add L_{CC} package. Remove vendors 27014, 07263, and REV PAGE REV С С С С С С **REV STATUS** 10 OF PAGES PAGES 9 8 MILITARY DRAWING **Defense Electronics** This drawing is available for use by **Supply Center** all Departments and Agencies of the Dayton, Ohio Department of Defense MICROCIRCUITS, DIGITAL, LOW POWER SCHOTTKY TTL, COUNTER, Original date of drawing: MONOLITHIC SILICON 24 November 1976 CODE IDENT. NO. DWG NO. SIZE 76034 14933 OF REV AMSC N/A PAGE 12 5962-E253

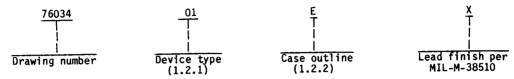
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DESC FORM 193 MAY 86



1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".

1.2 Part number. The complete part number shall be as shown in the following example:



1.2.1 Device type. The device type shall identify the circuit function as follows:

Device type	Generic number	Circuit function
01	54LS163	Synchronous 4-bit decade counter with synchronous clear

1.2.2 <u>Case outlines</u>. The case outlines shall be as designated in appendix C of MIL-M-38510, and as follows:

Outline letter

E
D-2 (16-lead, 1/4" x 7/8"), dual-in-line package
F-5 (16-lead, 1/4" x 3/8"), flat package
C-2 (20-terminal .350" x .350"), square chip carrier package

1.3 Absolute maximum ratings.

1.4 Recommended operating conditions.

Supply voltage (V_{CC}) - - - - - - - - - - - 4.5 V dc minimum to 5.5 V dc maximum Minimum high-level input voltage (V_{IH}) - - - - - 2.0 V dc Maximum low-level input voltage (V_{IL}) - - - - - - - - - - - - - - - 55°C to +125°C

1/ Must withstand the added $P_{\bar{D}}$ due to short-circuit test (e.g., I_{OS}). 2/ When a thermal resistance is specified in MIL-M-38510, appendix C, that value shall supersede the value specified herein.

MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO	SIZE	14933	DWG NO.	76034	
		REV (PAGE	2



2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510

- Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883

Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

- 3.1 <u>Item requirements</u>. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 <u>Design</u>, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
 - 3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.2 Truth table. The truth table shall be as specified on figure 2.
 - 3.2.3 Logic diagram. The logic diagram shall be as specified on figure 3.
 - 3.2.4 <u>Case outlines</u>. The case outlines shall be in accordance with 1.2.2 herein.
- 3.3 Electrical performance characteristics. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full recommended case operating temperature range.
- $3.4\,$ Marking. Marking shall be in accordance with MIL-STD-883 (see $3.1\,$ herein). The part shall be marked with the part number listed in $1.2\,$ herein. In addition, the manufacturer's part number may also be marked as listed in $6.4\,$ herein.
- 3.5 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.
- 3.6 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.

MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO	SIZE A	10ENT.	NO.	DWG NO	76034	
		REV	С		PAGE	3

				Cueur A	Li	mits	Unit
Test	Symbol 	-55°C unless ot	onditions < T _{C <} +125°C nerwise specified	Group A subgroups 	Min	Max	01111
High-level output voltage	v _{OH} 	V _{CC} = 4.5 V; V _{IN} = 0.7 V	I _{OH} = -400 μA or 2.0 V	1,2,3	2.5	 	٧
Low-level output voltage	I V _{OL}	V _{CC} = 4.5 V; V _{IN} = 0.7 V	$I_{0L} = 4 \text{ mA}$ or 2.0 V	1,2,3		 0.4 	٧
Input clamp voltage	IV _{IC}	V _{CC} = 4.5 V; T _C = +25 °C	I _{IN} = -18 mA	1		 -1.5 	٧
High-level input current at data or enable P	IIIH1	V _{CC} = 5.5 V,	V _{IN} = 2.7 V	1,2,3		20 	μА
	 I _{I H2} 	V _{CC} = 5.5 V,	V _{IN} = 5.5 V	1,2,3		 100 	μА
High-level input current at load, clock, enable T, or	I _{IH3}	V _{CC} = 5.5 V,	V _{IN} = 2.7 V	1,2,3	<u> </u>	40	μА
clear	I I H4	V _{CC} = 5.5 V,	V _{IN} = 5.5 V	1,2,3		200	μА
Low-level input current at data or enable P	I IL1	V _{CC} = 5.5 V,	V _{IN} = 0.4 V	1,2,3		40	mA
Low-level input current at load, enable T, or clear	I _{IL2}	V _{CC} = 5.5 V,	V _{IN} = 0.4 V	1,2,3		80	mA
Low-level input current at clock	I _{IL3}	V _{CC} = 5.5 V,	V _{IN} = 0.4 V	1,2,3		-1.2	mA
Short-circuit output current	Ios	V _{CC} = 5.5 V V _{OUT} = 0.0 V	1/	1,2,3	-15	-130	mA
Current supply	ICCH	V _{CC} = 5.5 V		1,2,3	 	31	mA
	ICCL	V _{CC} = 5.5 V		1,2,3		32	mA
Functional tests	1	See 4.3.1c		7		<u> </u>	
Maximum clock frequency	f _{MAX}	$V_{CC} = 5.0 \text{ V}$ $ R_1 = 2 \text{ k}\Omega \pm 59$	C _L = 15 pF ±10%	9	25		MHz
	1			10,11	15		MHz
			C _L = 50 pF ±10%	9	20		MHz
See footnotes at end of table	<u> </u>		<u>i</u>	10,11	13		MUZ
See Touchores at end of rable	•	SIZE C	ODE IDENT. NO.	DWG NO.			
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DEFENSE ELECTRONICS SUPPLY DAYTON, OHIO	CENTER		REV C	PAG	E	4	

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	10		17.4.4	10	Lim	iits	11= 2.4
Test	Symbol 	-55°C <	ditions T _{C ≤} +125°C rwise specified	Group A subgroups 	Min	Max	Unit
Propagation delay time, high-to-low level	 t _{PHL1} 	V _{CC} = 5.0 V R _L = 2 kΩ ±5%	 C _L = 15 pF ±10%	9		35	ns
output from clock to ripple carry 2/	 	 		10,11	 	49	l ns I
	j I	i 	ic _L = 50 pF ±10%	j 9 j	 	40	l ns
		 - -		10,11		56	ns
Propagation delay time, low-to-high level	t _{PLH1}		C _L = 15 pF ±10%	9		35	ns
output from clock to ripple carry 2/	İ	į Į	<u> </u>	10,11		49	l ns
· ·		 	 C _L = 50 pF ±10%	9		40	l ns
			i 1	10,11		56	ns
Propagation delay time, it high-to-low level output from clock (load input high) to any Q 2/	tpHL2	- 	C _L = 15 pF ±10%	9		27	ns
			1 	10,11		38	ns
		1	C _L = 50 pF ±10%	9		32	ns
	i		1	10,11		42	ns
Propagation delay time, l	t _{PLH2}	-1 	C _L = 15 pF ±10%	9 1		24	l I ns
output from clock (load input high) to any Q 2/			 	10,11		34	ns
_			C _L = 50 pF ±10%	9		29	l l ns
	Ì	1	 	10,11		38	ns
Propagation delay time,	t _{PHL3}	- - -		9		29	ns
high-to-low level output from clock (load input low) to any Q 2/	i i		 	10,11		49	ns ľ
· · · · · ·	!		C _L = 50 pF ±10%	j 9		34	l ns
			 	10,11		48	ns
See footnotes at end of tabl	e.						
MILITARY DRAW	ING	SIZE CO	DE IDENT. NO. D	WG NO.	5034		
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO			REV C	PAG	E	5	

TABLE I.	Electric	al performance char	acteristics - (Continued.			
Test	Symbol	Condition	ons	 Group A	Lin	nits	Unit
1630		-55°C < Tc <	$-55^{\circ}\text{C} < \text{T}_{\text{C}} < +125^{\circ}\text{C}$ unless otherwise specified			Max	
Propagation delay time, low-to-high level	t _{PLH3}		= 15 pF ±10%	9 1		25	ns
output from clock (load input low) to any Q 2/	1	-		10,11		35	ns
· —	1		= 50 pF ±10%	9		30	ns
	İ	i i		10,11		42	ns
Propagation delay time, high-to-low level	tpHL4	[]	= 15 pF ±10%	9		16	ns
output from enable T to ripple carry 2/	İ			10,11		22	ns
]]]	 	= 50 pF ±10%] 	21	ns
	İ 			10,11		29	ns
Propagation delay time, low-to-high level	t _{PLH4}		= 15 pF ±10%	9		16	ns
output from enable T to ripple carry 2/	İ	i i		10,11		22	ns
·· -	 	! 	= 50 pF ±10%	9	1	21	ns
	j I			10,11		29	ns
Propagation delay time, high-to-low level	t _{PHL5}]	= 15 pF ±10%	9] 	28	ns
output from clear to any Q 2/	! 			10,11		39 	ns
_	1	CL =	= 50 pF ±10%	9		33	ns

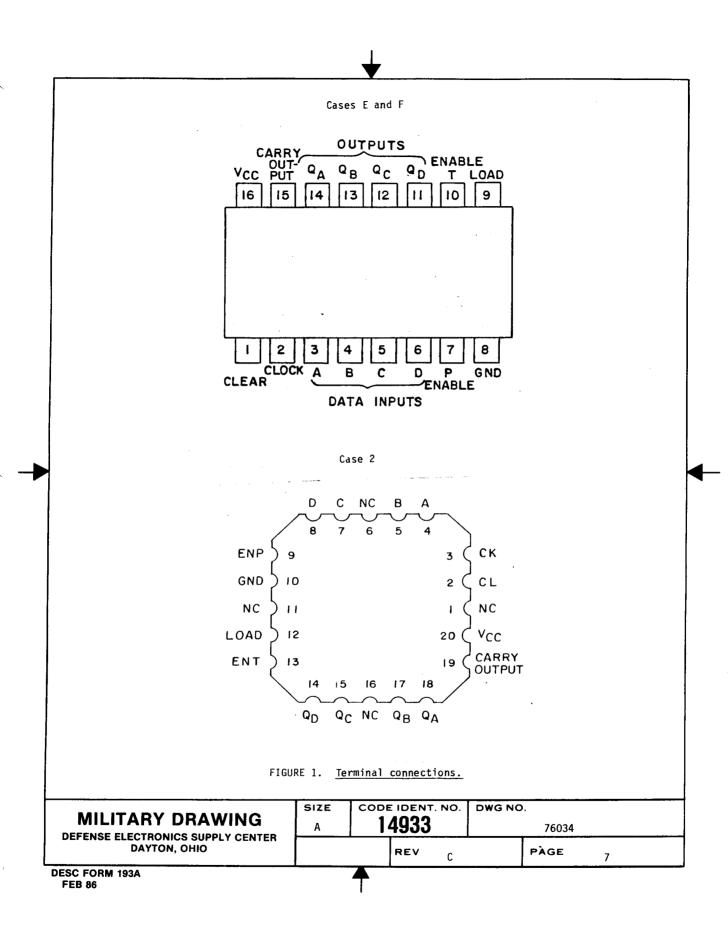
^{1/} Not more than one output should be shorted at a time, and the duration of the short-circuit condition should not exceed one second.

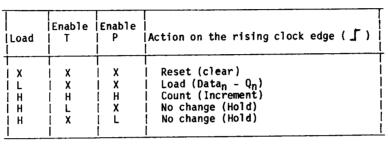
10,11

ns

MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO	SIZE A	14933	l	76034	
		REV C	PA	GE 6	

^{2/} Propagation delay time testing and maximum clock frequency testing may be performed using either $C_L = 15$ pF or $C_L = 50$ pF. However, the manufacturer must certify and guarantee that the microcircuits meet the switching test limits specified for a 50-pF load.



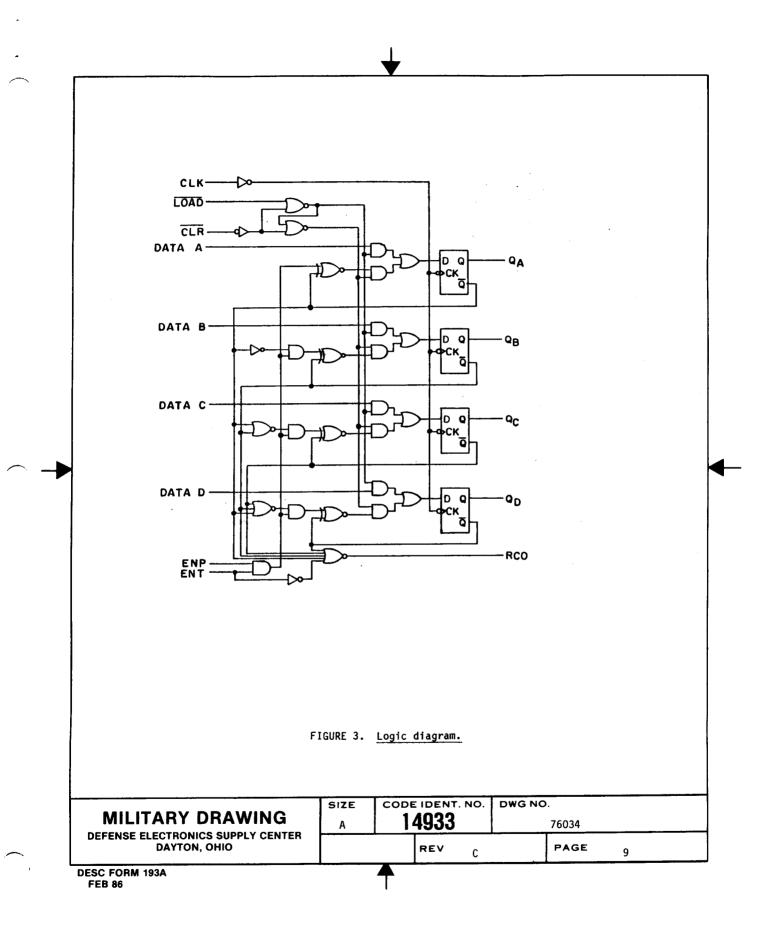


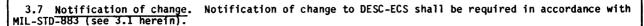
H = High voltage level
L = Low voltage level
X = Don't care

FIGURE 2. Truth table.

DWG NO. CODE IDENT. NO. SIZE **MILITARY DRAWING** 14933 76034 **DEFENSE ELECTRONICS SUPPLY CENTER** DAYTON, OHIO REV PAGE С 8 **DESC FORM 193A**

FEB 86





- 3.8 Verification and review. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
 - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - a. Burn-in test (method 1015 of MIL-STD-883).
 - Test condition A, B, C, or D, using the circuit submitted with the certificate of compliance (see $3.5\ \text{herein}$).
 - $T_A = +125^{\circ}C$, minimum. (2)
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-SID-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
 - 4.3.1 Group A inspection.
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 4, 5, 6, and 8 in table I, method 5005 of MIL-STD-883 shall be omitted.
 - c. Subgroup 7 tests shall verify the truth table.
 - 4.3.2 Groups C and D inspections.
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. Steady-state life test (method 1005 of MIL-STD-883) conditions:
 - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see $\,$ 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by appendix B of MIL-M-38510 and method 1005 of MIL-STD-883.

MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO	SIZE A	14933	DWG NO. 76034
		REV C	PAGE 10

DESC FORM 193A

FEB 86

TABLE II. <u>Electrical test requirements</u>.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters ((method 5004)	
Final electrical test parameters (method 5004)	1*, 2, 3, 9
Group A test requirements (method 5005)	1, 2, 3, 7, 9 10, 11**
Groups C and D end-point electrical parameters (method 5005)	1, 2, 3

* PDA applies to subgroup 1.

** Subgroups 10 and 11, if not tested, shall be guaranteed to the specified limits in table I.

5. PACKAGING

- 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.
- 6. NOTES
- 6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.
 - 6.2 Replaceability. Replaceability is determined as follows:
 - a. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
 - b. When a QPL source is established, the part numbered device specified in this drawing will be replaced by the microcircuit identified as part number M38510/31512B--.
- 6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, OH 45444, or telephone 513-296-5375.

MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO	SIZE A	14933	DWG NO. 76034	
		REV C	PAGE 11	

6.4 Approved sources of supply. Approved sources of supply are listed herein. Additional sources will be added as they become available. The vendors listed herein have agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

Military drawing part number	Vendor CAGE number	Vendor similar part number <u>1</u> /	Replacement military specification part number
7603401EX <u>2</u> /	01295 18324 04713	SNJ54LS163AJ 54LS163A/BEA 54LS163ABEXJC	M38510/31512BEX
7603401FX <u>2</u> /	01295 18324 04713	 SNJ54LS163AW 54LS163A/BFA 54LS163ABFXJC	M38510/31512BFX
76034012X <u>2</u> /	01295 18324 04713	SNJ54LS163AFK 54LS163A/B2C 54LS163AM/B2XJC	M38510/31512B2X

 $[\]frac{1}{}$ CAUTION. Do not use this number for item acquisition. Items acquired to the vendor similar part number only may not satisfy the performance requirements of this drawing.

2/ Inactive for new design. Use QPL-38510 product.

Vendor CAGE number	Vendor name and address
01295	Texas Instruments, Inc. P.O. Box 6448 Midland, TX 79701
18324	Signetics Corporation 4130 South Market Court Sacramento, CA 95834
04713	Motorola, Inc. 7402 S. Price Road Tempe, AZ 85283

MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO	SIZE	14933	DWG NO. 76034		
		REV	С	PAGE	12

DESC FORM 193A FEB 86

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